-40V PNP POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -40V
- I_C = -3A High Continuous Current
- I_{CM} = -5A Peak Pulse Current
- Very Low $V_{CE(sat)}$ < -220mV at -1A
- $R_{CE(sat)}$ = 66mΩ at -3A
- P_D = 2W
- Complimentary Part – FCX1051A
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

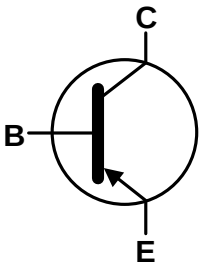
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.052 grams (Approximate)

Applications

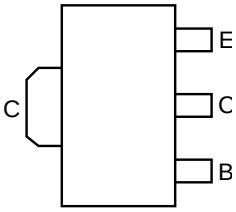
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC-DC Modules
- Backlight Inverters
- Power Switches
- MOSFET Gate Drivers

SOT89

Top View



Device Symbol



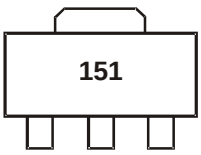
Top View
Pin-Out

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FCX1151ATA	AEC-Q101	151	7	12	1,000

Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



151 = Product Type Marking Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-45	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Continuous Collector Current	I_C	-3	A
Peak Pulse Current	I_{CM}	-5	A
Base Current	I_B	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

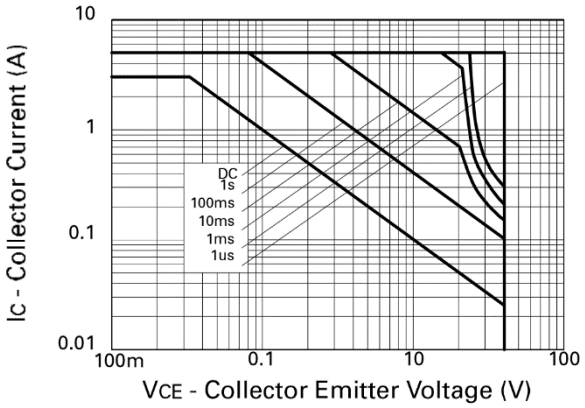
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	1	W
	(Note 6)		1.6	
	(Note 7)		2.0	
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{\theta JA}$	125	°C/W
	(Note 6)		78	
	(Note 7)		62.5	
Thermal Resistance, Junction to Lead	(Note 8)	$R_{\theta JL}$	3.6	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 9)

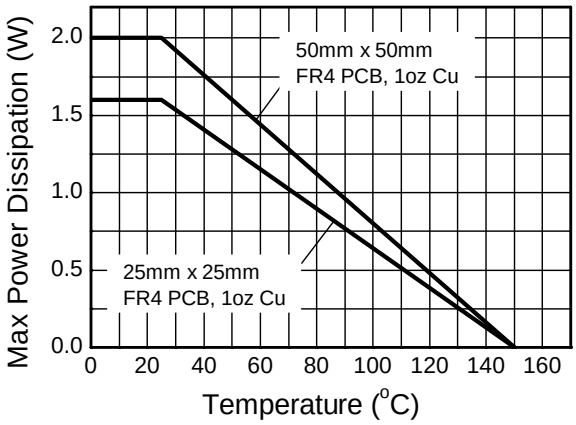
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
7. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
8. Thermal resistance from junction to solder-point (on the exposed collector pad).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

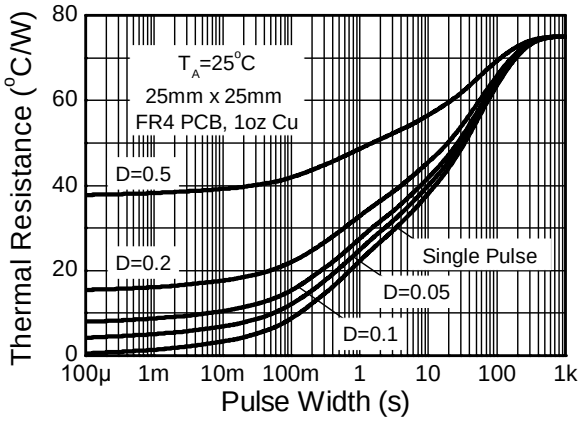
Thermal Characteristics and Derating Information



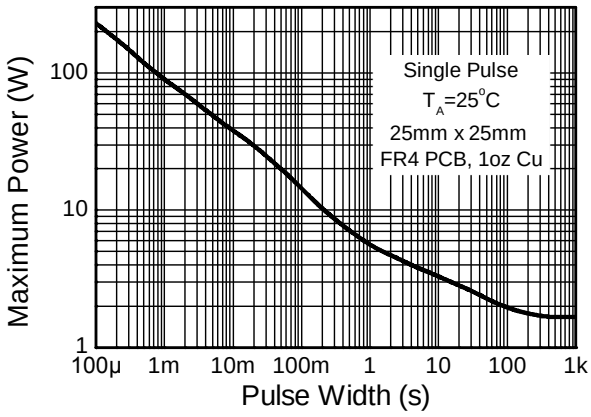
Safe Operating Area



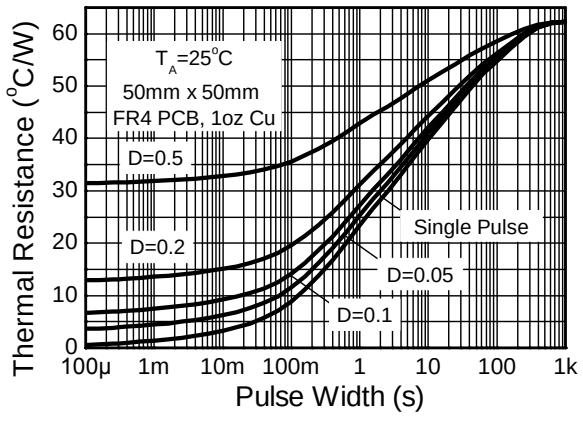
Derating Curve



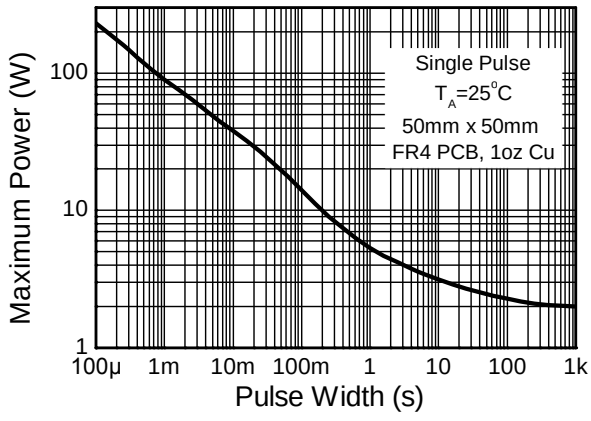
Transient Thermal Impedance



Pulse Power Dissipation

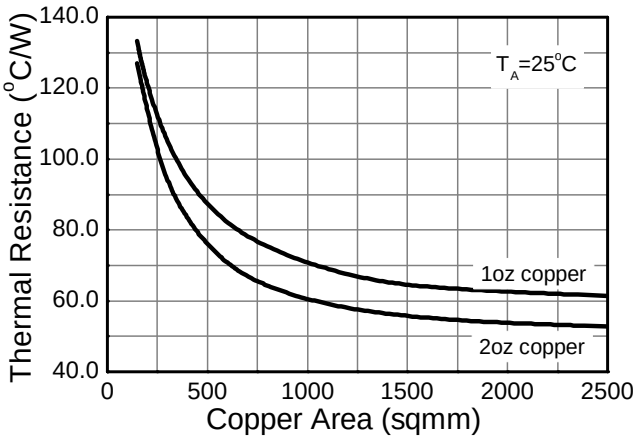


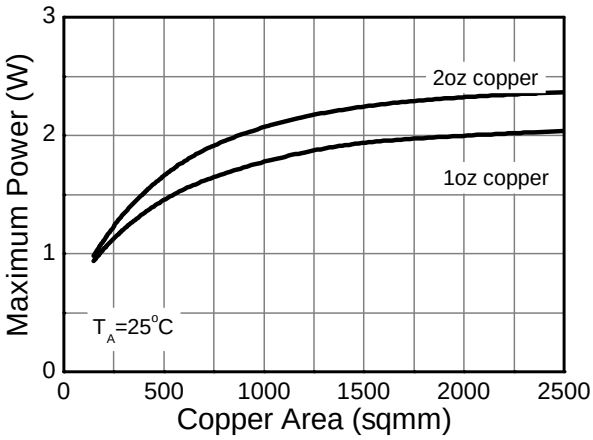
Transient Thermal Impedance



Pulse Power Dissipation

Thermal Characteristics and Derating Information (Cont.)



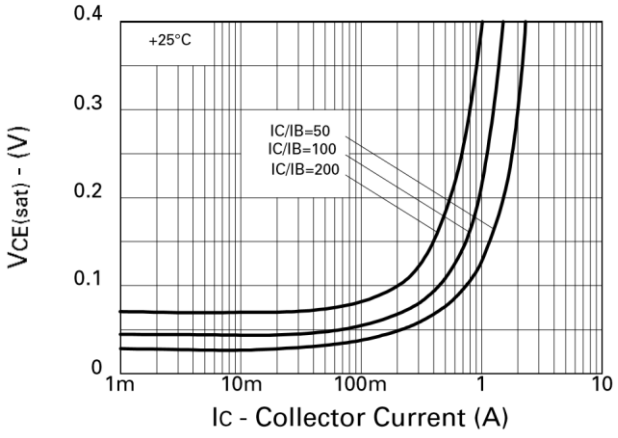


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

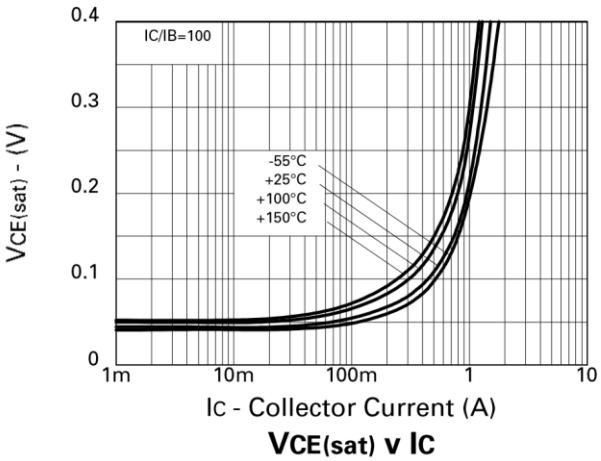
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-45	—	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage	BV_{CES}	-40	—	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-40	—	—	V	I_C = -10mA
Collector-Emitter Breakdown Voltage	BV_{CEV}	-40	—	—	V	I_C = -100µA, V_{EB} = 1V
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	—	—	V	I_E = -100µA
Collector Cutoff Current	I_{CBO}	—	-0.3	-100	nA	V_{CB} = -36V
Collector Cutoff Current	I_{CES}	—	-0.3	-100	nA	V_{CES} = -32V
Emitter Cutoff Current	I_{EBO}	—	-0.3	-100	nA	V_{EB} = -4V
DC Current Transfer Static Ratio (Note 10)	h_{FE}	270 250 180 100 -	450 400 300 190 45	- 800 - - -	—	I_C = -10mA, V_{CE} = -2V I_C = -0.5A, V_{CE} = -2V I_C = -2A, V_{CE} =-2V I_C = -3A, V_{CE} = -2V I_C = -5A, V_{CE} = -2V
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	—	-60 -120 -140 -200	-90 -180 -220 -300	mV	I_C = -0.1A, I_B = -1mA I_C = -0.5A, I_B = -5mA I_C = -1A, I_B = -20mA I_C = -3A, I_B = -250mA
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	—	-985	-1050	mV	I_C = -3A, I_B = -250mA
Base-Emitter Turn-on Voltage (Note 10)	$V_{BE(on)}$	—	-850	-950	mV	I_C = -3A, V_{CE} = -2V
Transitional Frequency	f_T	—	145	—	MHz	I_C = -50mA, V_{CE} = -10V, f = 50MHz
Output Capacitance	C_{obo}	—	40	—	pF	V_{CB} = -10V, f = 1MHz
Switching Time	t_{on}	—	170	—	ns	V_{CC} = -30V, I_C = -2A, I_{B1} = I_{B2} = ±20mA
	t_{off}	—	460	—	ns	

Note: 10. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.

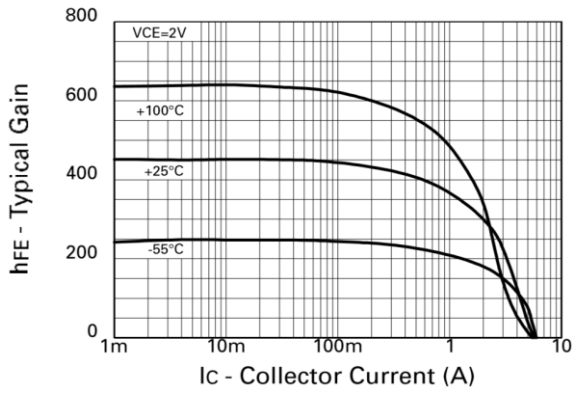
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



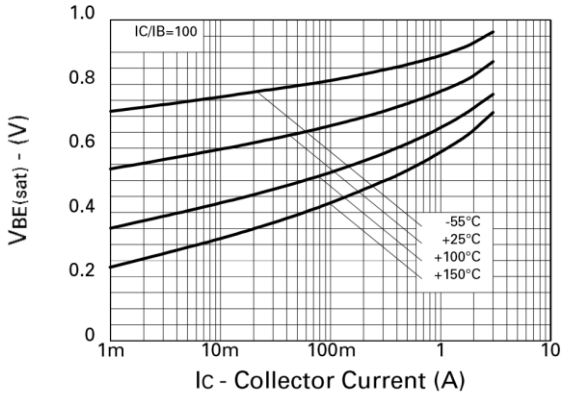
VCE(sat) v IC



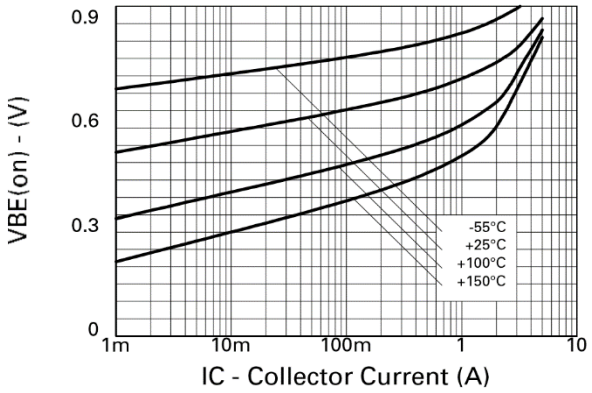
VCE(sat) v IC



hFE v IC



VBE(sat) v IC

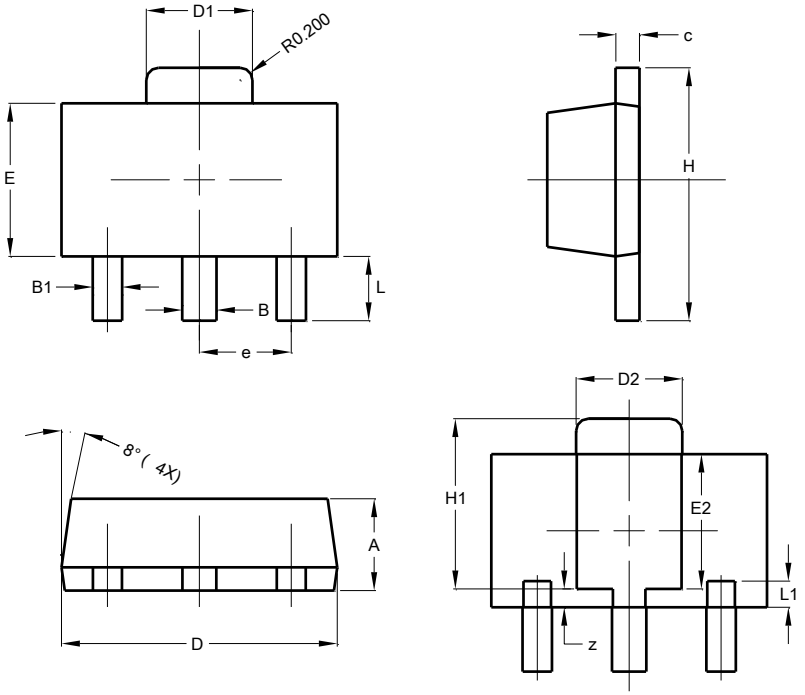


VBE(on) v IC

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

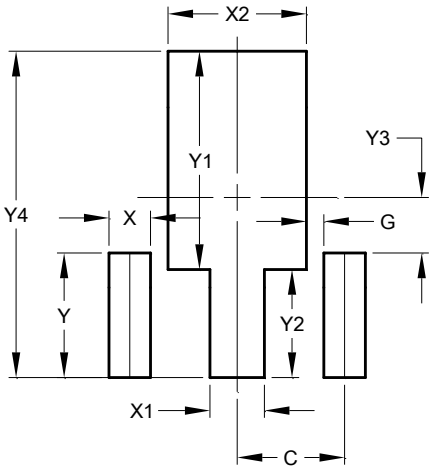


SOT89			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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